

AMP3085 SOLID STATE HIGH POWER AMPLIFIER

FEATURES

Class A/AB linear design
High Power Advanced technology devices
Instantaneous wide bandwidth
Suitable for all single channel modulation standards
Small form factor & light weight
Built-in monitoring & protection circuits
High efficiency, with unprecedented reliability and ruggedness



ELECTRICAL SPECIFICATIONS: 50Ω, 25°C

Parameter	Specification	Notes
Operating Frequency Range	8.0 - 12.0 GHz	
Power Output @ Psat	100 Watt Min / 120 Watt Typ	CW
Power Gain	50 dB Min	0dBm or less for rated Pout
Power Gain Flatness	3.0 dB p-p Max	Constant input power
Input Return Loss	-10 dB Max	
Harmonics	-25 dBc Max	At rated Pout
Spurious	-60 dBc Max	Non-harmonics
Noise Figure	10 dB Max	
Operating Voltage	32 VDC Nom	
Current Consumption	23 Amp Max / <20 Amp Typ	At rated Pout
Input Power Protection	+3 dBm Max	<10 Sec without damage
Load VSWR Protection	5 : 1 Max	<1 minute at rated Pout

ENVIRONMENTAL CHARACTERISTICS

Parameter	Specification	Notes
Operating Case Temperature	-20 to +75 °C ²	
Storage Temperature	-40 to +85 °C	
Relative Humidity	up to 95 %	Non-condensing
Altitude	3000 meters	
Shock & Vibration	Normal transport ¹	

1 MIL Spec available for quotation

MECHANICAL SPECIFICATIONS

Parameter	Specification	Notes
Dimensions L x W x H	180 x 200 x 27 mm	Excluding connectors
Weight	4 Kg.	
RF Connectors In/Out	SMA female / Type-N female	
DC Power / Interface Connector	7-Pin Hybrid D-Sub	
Cooling	External Heatsink ²	Forced air required

2. Proper cooling is require to insure thermal rise doesn't exceed the specified operating case temperature due to module power & power consumption.

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D-SUB CONNECTOR PIN ASSIGNMENT

Pin	Function	Description
1	N/A	N/A
2	N/A	N/A
3	Current Sensor	$I_D @ 20\text{mV}/100\text{mA Typ}$
4	Temp Sensor	$V_T @ 10\text{mV}/^\circ\text{C} + 500\text{mV Typ}$
5	Shutdown	Enable = TTL "High" ($>3.2\text{V}$) or Open / Disable = TTL "Low" or Short
A1	VDD	32VDC
A2	GND	Ground

OUTLINE DRAWING

